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# FAN5037 Adjustable Switching Regulator Controller

## Features

- High power switch-mode DC-DC controller can provide in excess of 13A
- Output voltage adjustable from 1.2V to 3.6V
- 85% efficiency
- Cumulative accuracy < 3% over line, load, and temperature variations
- · Overvoltage and short circuit protection
- Built-in soft start
- No overshoot at turn-on

## Applications

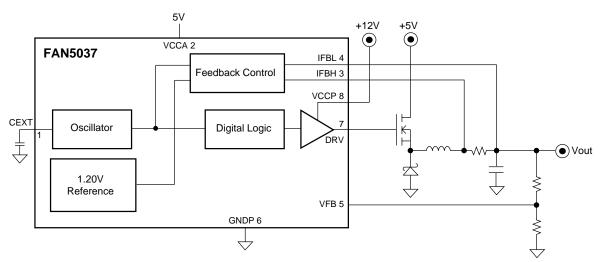
- I/O and AGP power for desktop computers
- High efficiency power for ASICs
- High efficiency power for DSPs
- Adjustable step-down power supplies

## Description

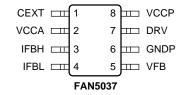
The FAN5037 is a high power, switch-mode DC-DC controller that provides efficient power for all low-voltage applications. This controller has a built-in Soft Start feature which offers system protection during power-up by reducing both inrush current and output overshoot. When combined with the appropriate external circuitry, the FAN5037 can deliver load currents as high as 13A at efficiencies as high as 88%. The FAN5037 can generate output voltages from 1.2V up to 3.6V using external resistors.

The FAN5037 is designed to operate in a constant on-time control mode under all load conditions. Its accurate low TC reference eliminates the need for precision external components in order to achieve the tight tolerance voltage regulation required by many applications. Short circuit current protection is provided through the use of a current sense resistor, while overvoltage protection is provided internally.

## **Block Diagram**



## **Pin Assignments**



## **Pin Descriptions**

| Pin<br>Name | Pin<br>Number | Pin Function Description   |
|-------------|---------------|--|
| CEXT        | 1             | <b>External capacitor.</b> A 180pF capacitor is connected to this pin as part of the constant on-time pulse width circuit. Careful layout of this pin is critical to system performance. See Applications Information for details.   |
| VCCA        | 2             | <b>Analog V<sub>cc</sub>.</b> Power supply for regulator control circuitry and voltage reference. Connect to system 5V supply and decouple to ground with $0.1\mu$ F ceramic capacitor.  |
| IFBH        | 3             | <b>High side current feedback.</b> Pins 3 and 4 are used as the inputs for the current feedback control loop and as the short circuit current sense points. Careful layout of the traces from these pins to the current sense resistor is critical for optimal performance of the short circuit protection scheme. See Applications Information for details. |
| IFBL        | 4             | Low side current feedback. See Applications Information for details.   |
| VFB         | 5             | <b>Voltage feedback.</b> Using two external resistors, this pin sets the output voltage level for the switching regulator.   |
| GNDP        | 6             | <b>Power Ground.</b> Connect to a low impedance ground. See Application Information for details.   |
| DRV         | 7             | <b>MOSFET driver output.</b> Connect this pin to the gate of the N-channel MOSFET Q1 as shown in Figure 12. The trace from this pin to the MOSFET gate should be kept as short as possible (less than 0.5"). See Applications Information for details.   |
| VCCP        | 8             | <b>Power Vcc.</b> Power supply for DRV output driver. Connect to system 12V supply with R-C filter shown in Figure 12. See Applications Information for details.   |

## **Absolute Maximum Ratings**

| Supply Voltages, VCCA                       | 7V            |
|---|---------------|
| Supply Voltages, VCCP                       | 13V           |
| Junction Temperature, TJ                    | +150°C        |
| Storage Temperature, TS                     | -65 to +150°C |
| Lead Soldering Temperature, 10 seconds      | 300°C         |
| Thermal Resistance Junction-to-Ambient, OJA | 163°C/W       |

Note:

1. Functional operation under any of these conditions is not implied. Performance is guaranteed only if Operating Conditions are not exceeded.

## **Operating Conditions**

| Parameter                         | Conditions | Min. | Тур. | Max. | Units |
|-----------------------------------|------------|------|------|------|-------|
| Switching Regulator Supply, VCCA  |            | 4.75 | 5    | 5.25 | V     |
| Ambient Operating Temperature, TA |            | 0    |      | 70   | °C    |
| Gate Drive Supply, VCCP           |            | 9.5  | 12   | 12.6 | V     |

## **Electrical Characteristics**

(VCCA = 5V, VCCP = 12V,  $T_A = 25^{\circ}C$  using circuit of Figure 1, unless otherwise noted)

The • denotes specifications which apply over the full ambient operating temperature range.

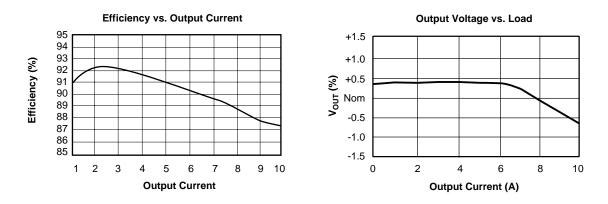
| Parameter                        | Conditions                         |   | Min. | Тур. | Max. | Units  |
|----------------------------------|------------------------------------|---|------|------|------|--------|
| Output Voltage                   |                                    |   | 1.2  |      | 3.6  | V      |
| Output Temperature Drift         | $T_{A} = 0^{\circ}C - 70^{\circ}C$ |   |      | 40   |      | ppm/°C |
| Line Regulation                  | VCCA = 4.75 to 5.25V, ILOAD = 13A  |   |      | 3    | 5    | mV     |
| Load Regulation                  | ILOAD = 0 to 5A or 5A to 13A       |   |      | 30   | 43   | mV     |
| VOUT PSRR                        | VCCA = 4.75 to 5.25V               |   | 60   |      |      | dB     |
| Output Ripple, peak-peak         | 20MHz BW, ILOAD = 13A              |   |      | 15   |      | mV     |
| Total DC Accuracy <sup>1</sup>   |                                    | • |      | ±55  | ±100 | mV     |
| Efficiency                       | ILOAD = 5A                         |   | 80   | 85   |      | %      |
| Output Driver Current            | Open Loop                          | • | 0.5  |      |      | A      |
| Short Circuit Threshold Voltage  |                                    | • | 70   | 90   | 100  | mV     |
| Undervoltage Lockout             |                                    | • | 3.5  | 4.0  | 4.5  | V      |
| On Time Pulse Width <sup>2</sup> | CEXT = 180pF                       |   |      | 3.5  |      | μs     |
| VCCA Supply Current              | Independent of load                | • |      | 5    | 15   | mA     |
| VCCP Supply Current              | ILOAD = 13A                        | • |      | 20   | 25   | mA     |

Notes:

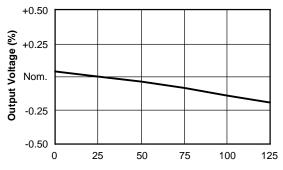
1. Total DC accuracy includes setpoint accuracy, temperature drift, line and load regulation.

2. The on-time pulse width of the oscillator is set via external capacitor CEXT.

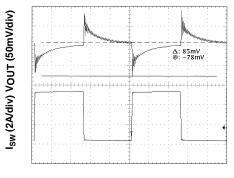
**Typical Operating Characteristics** (VCCA = 5V, and T<sub>A</sub> = +25°C using circuit in Figure 1, unless otherwise noted)





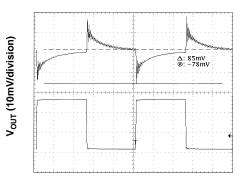


Transient Response, 0.5 to 5.5A



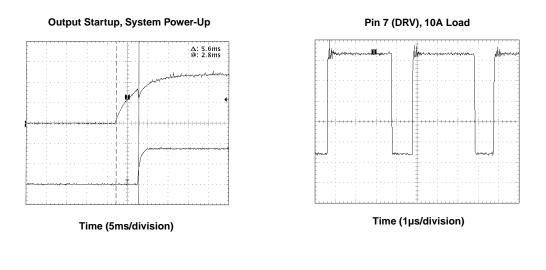
Time (100µs/division)

Output Ripple, I<sub>OUT</sub> = 10A)

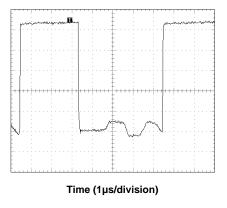


Time (2µs/division)

## Typical Operating Characteristics (continued)



Pin 7 (DRV), 0.1A Load



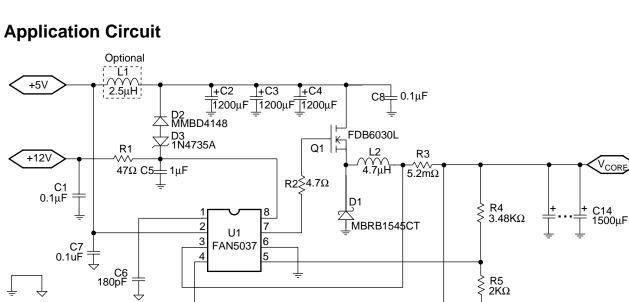
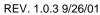


Figure 1. 13A at 3.3V Application Schematic



| Qty.     | Reference | Manufacturer<br>Part Order # | Description                            | Requirements<br>and Comments                         |  |  |
|----------|-----------|------------------------------|--|--|--|--|
| 3        | C1, C7-8  | Any                          | 100nF, 25V Capacitor                   |  |  |  |
| 3        | C2-4      | Sanyo<br>10MV1200GX          | 1200µF, 10V Aluminum Capacitor         | IRMS = 2A , See Equation<br>(2) in Applications      |  |  |
| 1        | C5        | Any                          | 1µF, 25V Capacitor                     |  |  |  |
| 1        | C6        | Any                          | 180pF, 50V Capacitor                   | COG  |  |  |
| 6        | C9-14     | Sanyo<br>6MV1500GX           | 1500µF, 6.3V Aluminum Capacitor        | ESR = 44mΩ   |  |  |
| 1        | R1        | Any                          | 47.5Ω                                  |  |  |  |
| 1        | R2        | Any                          | 4.75Ω                                  |  |  |  |
| 1        | R3        | N/A                          | 5.2mΩ, 1W Resistor                     | PCB Trace Resistor, see<br>Equation (3) Applications |  |  |
| 1        | R4        | Any                          | 3.48ΚΩ                                 |  |  |  |
| 1        | R5        | Any                          | 2ΚΩ                                    |  |  |  |
| 1        | D1        | Motorola<br>MBRB1545CT       | 15A, 45V Schottky                      |  |  |  |
| 1        | D2        | Fairchild<br>MMBD4148        | Signal Diode                           |  |  |  |
| 1        | D3        | Motorola<br>1N4735A          | 6.2V Zener                             |  |  |  |
| 1        | Q1        | Fairchild<br>FDB6030L        | $30V$ , $14m\Omega$ Logic Level MOSFET |  |  |  |
| Optional | L1        | Any                          | 2.5µH Inductor                         | ISAT > 8A  |  |  |
| 1        | L2        | Any                          | 4.7µH Inductor                         | ISAT > 13A   |  |  |
| 1        | U1        | Fairchild<br>FAN5037M        | PWM Controller                         |  |  |  |

#### Table1. Bill of Materials for a FAN5037 3.3V, 13A Application

## **Application Information**

The FAN5037 contains a precision trimmed zero TC voltage reference, a constant-on-time architecture controller, a high current output driver, and a low offset error amp. The detailed block diagram in Figure 1 shows how the FAN5037 works together with external components to achieve a high-performance switching power supply.

### Switch-Mode Control Loop

The main control loop for the switch-mode converter consists of a current conditioning amplifier and a voltage conditioning amplifier. The voltage amplifier compares the voltage from the internal reference with the converter's output voltage divided by an external resistor divider. The current amplifier senses the current by comparing the voltages at the IFBH and IFBL pins, which are attached to either side of the current sense resistor. The signals from the voltage and current amplifiers are summed together, the result being used to control the off-time of the oscillator. The current feedback signal is also used as part of the FAN5037 short-circuit protection.

#### **High Current Output Drivers**

The FAN5037 high current output driver (DRV) contains high speed bipolar power transistors configured in a push-pull configuration. The output driver is capable of supplying 0.5A of current in less than 100ns. The driver's power and ground are separated from the overall chip power and ground for added switching noise immunity.

#### Internal Reference

The reference in the FAN5037 is a precision band-gap type reference. Its temperature coefficient is trimmed to provide a near zero TC.

#### **Constant-On-Time Oscillator**

The FAN5037 switch-mode oscillator is designed as a fixed on-time, variable off-time oscillator. The constant-on-time oscillator consists of a comparator, an external capacitor, a fixed current source, a variable current source, and an analog switch that selects between two threshold voltages for the comparator. The external timing capacitor is alternately charged and discharged through the enabling and disabling of the fixed current source. The variable current source is controlled from the error inputs that are received from the current and voltage feedback signals. The oscillator off-time is controlled by the amount of current that is available from the variable current source to charge the external capacitor up to the high threshold level of the comparator. The on-time is set by the constant current source that discharges the external capacitor voltage down to the lower comparator threshold.

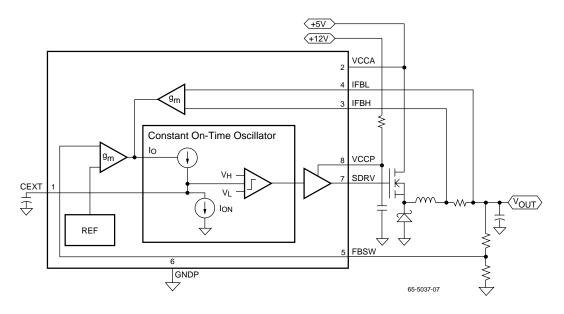


Figure 2. FAN5037 Detailed Block Diagram

#### **Output Voltage Selection**

The FAN5037 precision reference is trimmed to be 1.2V nominally. When using the FAN5037, the system designer has complete flexibility in choosing the output voltage for one regulator from 1.2V to 3.6V. This is done by appropriately selecting the feedback resistors. These could be 0.1% resistors to realize optimum output accuracy. The following equations determines the output voltage of the regulator:

$$V_{OUT} = 1.2 \times \left(\frac{R4 + R5}{R5}\right) \tag{1}$$

For example, for 3.3V:

$$V_{OUT} = 1.2 \times \left(\frac{R4 + R5}{R5}\right) = 1.2 \times \left(\frac{3.48k + 2.0k}{2.0k}\right) = 3.3V$$

#### **Input Capacitors**

The number of input capacitors required for the FAN5037 is dependent on their ripple current rating, which assures their rated life. The number required may be determined by

No. Caps = 
$$\frac{I_{out}^* \sqrt{DC - DC^2}}{I_{rating}}$$
(2)

where the duty cycle  $DC = (V_{out} + V_{f,diode}) / V_{in}$ . For example, with a 1.5V output at 10A, 5V input, and using the Sanyo capacitors specified in Table 1 which have a 2A ripple current rating, we have DC = (1.5 + .5)/5 = 0.4, and

No. Caps = 
$$\frac{10*\sqrt{0.4-0.4}^2}{2}$$
 = 2.44

so that we need 3 input capacitors.

#### Short Circuit Considerations

The FAN5037 uses a current sensing scheme to limit the load current if an output fault condition occurs. The current sense resistor carries the peak current of the inductor, which is greater than the maximum load current due to ripple current flowing in the inductor. The FAN5037 will begin to limit the output current to the load by reducing the duty cycle of the top-side MOSFET driver when the voltage across the current-sense resistor exceeds the short circuit comparator threshold voltage (Vth). When this happens the output voltage will temporarily go out of regulation. As the voltage across the sense resistor becomes larger, the duty cycle of the top-side MOSFET will continue to be reduced until the current limit value is reached. At this point, the FAN5037 will continuously deliver the limit current at a reduced output voltage level. The short circuit comparator threshold voltage is typically 90mV, with a tolerance of  $\pm 10$ mV. The ripple current flowing through the inductor in Figure 1 is 0.6Apeak. Refer to Application Note AB-23 for detailed discussions. The sense resistor value can be approximated as follows:

$$R_{\text{SENSE}} = \frac{V_{\text{th,min}}}{I_{\text{PK}}} \times (1 - \text{TF}) = \frac{V_{\text{th,min}}}{0.6\text{A} + I_{\text{LOAD,MAX}}} \times (1 - \text{TF})$$
(3)

where TF = Tolerance Factor for the sense resistor and 0.6A accounts for the inductor ripple current.

Since the value of the sense resistor is often less than  $10m\Omega$ , care should be taken in the layout of the PCB. Trace resistance can contribute significant errors. The traces to the IFBH and IFBL pins of the FAN5037 should be Kelvin connected to the pads of the current-sense resistor. To minimize the influence of noise, the two traces should be run next to each other.

#### **Schottky Diode**

In Figure 1, MOSFET Q1 and flyback diode D1 are used as complementary switches in order to maintain a constant current through the output inductor L2. As a result, D1 will have to carry the full current of the output load when the power MOSFET is turned off. The power in the diode is a direct function of the forward voltage at the rated load current during the off time of the FET. The following equation can be used to estimate the diode power:

 $P_{DIODE} = I_D \times V_D \times (1 - DutyCycle)$ 

where  $I_D$  is the forward current of the diode,  $V_D$  is the forward voltage of the diode, and DutyCycle is defined the same as

Duty Cycle =  $\frac{Vout}{Vin}$ 

For the Motorola MBRB1545CT Rectifier in Figure 1,

 $P_{\text{DIODE}} = 10A \times 0.65 \times (1 - 73.1\%) = 1.75W$ 

It is recommended that the diode T0-220 package be attached to a heatsink.

#### **Board Design Considerations**

#### **MOSFET Placement**

Placement of the power MOSFET is critical in the design of the switch-mode regulator. The MOSFET should be placed in such a way as to minimize the length of the gate drive path from the FAN5037 SDRV pin. This trace should be kept under 0.5" for optimal performance. Excessive lead length on this trace will cause high frequency noise resulting from the parasitic inductance and capacitance of the trace. Since this voltage can transition nearly 12V in around 100nsec, the resultant ringing and noise would be very difficult to suppress. This trace should be routed on one layer only and kept well away from the "quiet" analog pins of the device: CEXT, IFBH, IFBL, and GND. Refer to Figure 2. A 4.7 $\Omega$  resistor in series with the MOSFET gate can decrease this layout criticality. Refer to Figure 1.

#### Inductor and Schottky Diode Placement

The inductor and fly-back Schottky diode need to be placed close to the source of the power MOSFET for the same reasons stated above. The node connecting the inductor and Schottky diode will swing between the drain voltage of the FET and the forward voltage of the Schottky diode. It is recommended that this node be converted to a plane if possible. This node will be part of the high current path in the design, and as such it is best treated as a plane in order to minimize the parasitic resistance and inductance on that node. Since most PC board manufacturers utilize 1/2 oz copper on the top and bottom signal layers of the PCB, it is not recommended to use these layers to route the high current portions of the regulator design. Since it is more commonded to use those layers to route the high current paths in the design.

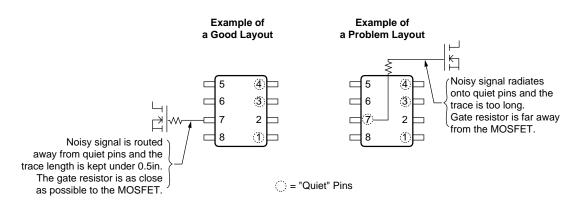


Figure 3. Examples of good and poor layouts

#### **Power and Ground Connections**

The connection of VCCA to the 5V power supply plane should be short and bypassed with a  $0.1\mu$ F directly at the VCCA pin of the FAN5037. The ideal connection would be a via down to the 5V power plane. A similar arrangement should be made for the VCCP pin that connects to +12V. Each ground should have a separate via connection to the ground plane below.

A 12V power supply is used to bias the VCCP. A  $47\Omega$  resistor is used to limit the transient current into VCCP. A 1uF capacitor filter is used to filter the VCCP supply and source the transient current required to charge the MOSFET gate capacitance. This method provides sufficiently high gate bias voltage to the MOSFET (VGS), and therefore reduces RDS(ON) of the MOSFET and its power loss.

Figure 4 provides about 5V of gate bias which works well when using typical logic-level MOSFETs. Non-logic-level MOSFETs should not be used because of their higher RDS(ON).

#### **MOSFET Gate Bias**

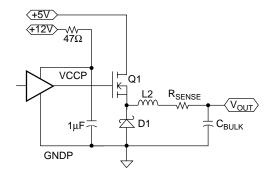
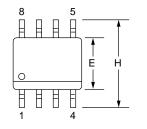


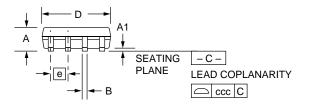
Figure 4. 12V Gate Bias Configuration

## **Mechanical Dimensions**

### 8 Lead SOIC Package

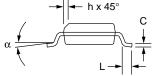
| Symbol | Inc      | Inches |          | neters | Notes |
|--------|----------|--------|----------|--------|-------|
| Symbol | Min.     | Max.   | Min.     | Max.   | Notes |
| А      | .053     | .069   | 1.35     | 1.75   |       |
| A1     | .004     | .010   | 0.10     | 0.25   |       |
| В      | .013     | .020   | 0.33     | 0.51   |       |
| С      | .008     | .010   | 0.20     | 0.25   | 5     |
| D      | .189     | .197   | 4.80     | 5.00   | 2     |
| E      | .150     | .158   | 3.81     | 4.01   | 2     |
| е      | .050 BSC |        | 1.27 BSC |        |       |
| Н      | .228     | .244   | 5.79     | 6.20   |       |
| h      | .010     | .020   | 0.25     | 0.50   |       |
| L      | .016     | .050   | 0.40     | 1.27   | 3     |
| Ν      | 8        |        | 8        | 6      |       |
| α      | 0°       | 8°     | 0°       | 8°     |       |
| CCC    | _        | .004   | _        | 0.10   |       |





#### Notes:

- 1. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 2. "D" and "E" do not include mold flash. Mold flash or protrusions shall not exceed .010 inch (0.25mm).
- 3. "L" is the length of terminal for soldering to a substrate.
- 4. Terminal numbers are shown for reference only.
- 5. "C" dimension does not include solder finish thickness.
- 6. Symbol "N" is the maximum number of terminals.



## **Ordering Information**

| Product Number | Package    |  |  |
|----------------|------------|--|--|
| FAN5037M       | 8 pin SOIC |  |  |

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